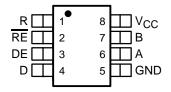
SN65MLVD200, SN65MLVD202 SN65MLVD204, SN65MLVD205 MULTIPOINT-LVDS LINE DRIVERS AND RECEIVERS

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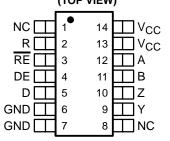
- Low-Voltage Differential 30-Ω Line Drivers and Receivers for Signaling Rates[†] up to 100 Mbps
- Power Dissipation at 100 Mbps
 - Driver: 50 mW TypicalReceiver: 30 mW Typical
- Meets or Exceeds Current Revision of M-LVDS Standard TIA/EIA-899 for Multipoint Data Interchange
- Controlled Driver Output Voltage Transition Times for Improved Signal Quality
- -1-V to 3.4-V Common-Mode Voltage Range Allows Data Transfer With up to 2 V of Ground Noise
- Type-1 Receivers Incorporate 25 mV of Hysteresis

- Type-2 Receivers Provide an Offset (100 mV) Threshold to Detect Open-Circuit and Idle-Bus Conditions
- Operates From a Single 3.3-V Supply
- Propagation Delay Times Typically 2.3 ns for Drivers and 5 ns for Receivers
- Power-Up/Down Glitch-Free Driver
- Driver Handles Operation Into a Continuous Short Circuit Without Damage
- Bus Pins High Impedance When Disabled or V_{CC} ≤ 1.5 V
- 200-Mbps Devices Available (SN65MLVD201, 203, 206, and 207)

SN65MLVD200D (Marked as MF200) SN65MLVD204D (Marked as MF204) (TOP VIEW)



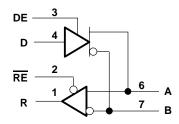
SN65MLVD202D (Marked as MLVD202) SN65MLVD205D (Marked as MLVD205) (TOP VIEW)



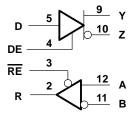
NC – No internal connection

logic diagram (positive logic)

SN65MLVD200, SN65MLVD204



SN65MLVD202, SN65MLVD205





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

†The signaling rate of a line is the number of voltage transitions that are made per second expressed in bps (bits per second) units.



description

This series of SN65MLVD20x devices are low-voltage differential line drivers and receivers complying with the proposed multipoint low-voltage differential signaling (M-LVDS) standard (TIA/EIA-899). These circuits are similar to their TIA/EIA-644 standard compliant LVDS counterparts, with added features to address multipoint applications. Driver output current has been increased to support doubly-terminated, $50-\Omega$ load multipoint applications. Driver output slew rates are optimized for signaling rates up to 100 Mbps.

Types 1 and 2 receivers are available. Both types of receivers operate over a common-mode voltage range of -1 V to 3.4 V to provide increased noise immunity in harsh electrical environments. Type-1 receivers have their differential input voltage thresholds near zero volts (±50 mV), and include 25 mV of hysteresis to prevent output oscillations in the presence of noise. Type-2 receivers include an offset threshold to detect open-circuit, idle-bus, and other fault conditions, and provide a known output state under these conditions.

The intended application of these devices is in half-duplex or multipoint baseband data transmission over controlled impedance media of approximately $100-\Omega$ characteristic impedance. The transmission media may be printed circuit board traces, backplanes, or cables. (Note: The ultimate rate and distance of data transfer is dependent upon the attenuation characteristics of the media, the noise coupling to the environment, and other application-specific characteristics).

These devices are characterized for operation from -40°C to 85°C.

AVAILABLE OPTIONS

NOMINAL SIGNALING RATE, Mbps	FOOTPRINT	RECEIVER TYPE	PART NUMBERT
100	SN75176	Type 1	SN65MLVD200D
100	SN75ALS180	Type 1	SN65MLVD202D
100	SN75176	Type 2	SN65MLVD204D
100	SN75ALS180	Type 2	SN65MLVD205D

[†] The D package is available taped and reeled. Add the R suffix to the device type (e.g., SN65MLVD200DR)

Function Tables

TVDE-1 DECEIVED (200, 202)

11PE-1 RECEIVER (200, 202)			
INPUTS	INPUTS		
$V_{ID} = V_A - V_B$	RE	R	
V _{ID} ≥ 50 mV	L	Н	
-50 mV < V _{ID} < 50 mV	L	?	
$V_{ID} \le -50 \text{ mV}$	L	L	
X	Н	Z	
X	Open	Z	
Open Circuit	L	?	

TYPE-2 RECEIVER (204, 205)

INPUTS	INPUTS	
$V_{ID} = V_A - V_B$	RE	R
V _{ID} ≥ 150 mV	L	Н
50 mV < V _{ID} < 150 mV	L	?
$V_{ID} \leq 50 \text{ mV}$	L	L
X	Н	Z
X	Open	Z
Open Circuit	L	L

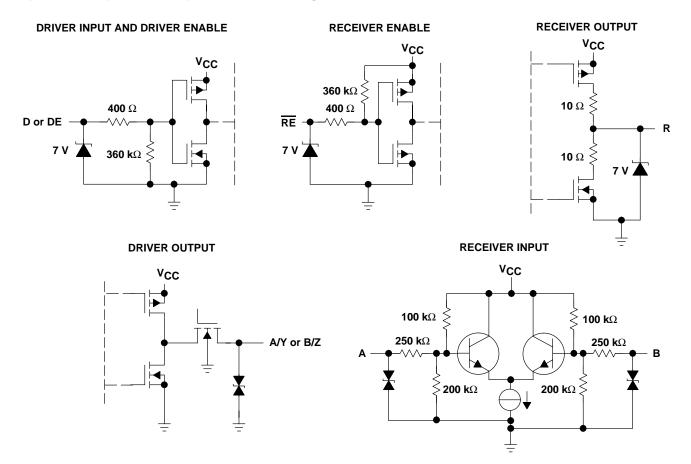
DRIVER

INPUT	ENABLE	OUTPUTS			
D	DE	A OR Y	B OR Z		
L	Н	L	Н		
Н	Н	Н	L		
OPEN	Н	L	Н		
Х	OPEN	Z	Z		
X	L	Z	Z		

H = high level, L = low level, Z = high impedance, X = Don't care, ? = indeterminate



equivalent input and output schematic diagrams



SN65MLVD200, SN65MLVD202 SN65MLVD204, SN65MLVD205 MULTIPOINT-LVDS LINE DRIVERS AND RECEIVERS

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absolute maximum ratings over operating free-air temperature (unless otherwise noted)

Supply voltage range, V _{CC} (see Note 1)	0.5 V to 4 V
Input voltage range: D, DE, RE	0.5 V to 4 V
A, B (200, 204)	–1.8 V to 4 V
A, B (202, 205)	–4 V to 6 V
Output voltage range: R	0.3 V to 4 V
Y, Z, A, or B	–1.8 V to 4 V
Electrostatic discharge: Human body model (see Note 2)	A, B, Y, or Z ±3 kV
	All pins ±2 kV
Charged-device model (see Note 3)	All pins±500 V
Continuous power dissipation	(see Dissipation Rating table)
Storage temperature range	65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 second	ds 260°C

[†] Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential I/O bus voltages, are with respect to network ground terminal.
 - 2. Tested in accordance with JEDEC Standard 22, Test Method A114-A.
 - 3. Tested in accordance with JEDEC Standard 22, Test Method C101.

DISSIPATION RATING

PACKAGE	T _A ≤ 25°C POWER RATING	OPERATING FACTOR ABOVE T _A = 25°C	T _A = 85°C POWER RATING		
D(8)	725 mW	5.8 mW/°C	377 mW		
D(14)	950 mW	7.6 mW/°C	494 mW		

recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}	3	3.3	3.6	V
High-level input voltage, V _{IH}	2		VCC	V
Low-level input voltage, V _{IL}	0		8.0	V
Magnitude of differential input voltage, V _{ID}	0.05		VCC	V
Voltage at any bus terminal, V_A , V_Y , $V_{Z, or} V_B$	-1.4		3.8	V
Common-mode input voltage V _{CM} , (V _A + V _B)/2	-1		3.4	V
Receiver load capacitance, C _L	5		15	pF
Operating free-air temperature, TA	-40		85	°C



device electrical characteristics over recommended operating conditions (unless otherwise noted)

		PARAMETER	TEST CONDITIONS	MIN†	TYP [‡]	MAX	UNIT
		Receiver disabled and driver enabled	$\overline{\text{RE}}$ and DE at V _{CC} , R _L = 50 Ω , All others open		13	22	
		Driver and receiver disabled RE at V _{CC} , DE at 0 V, R _L = No load, All others open			1	7	
ICC	Supply current	Receiver enabled and driver enabled	$\overline{\text{RE}}$ at 0 V, DE at V _{CC} , R _L = 50 Ω , All others open, No receiver load		16	26	mA
		Receiver enabled and driver disabled	RE at 0 V, DE at 0 V, All others open, No receiver load		4	11	

[†] The algebraic convention, in which the least positive (most negative) limit is designated as minimum, is used in this data sheet.

driver electrical characteristics over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN†	TYP‡ MAX	UNIT
V _{AB} or V _{YZ}	Differential output voltage magnitude	See Figure 2	480	650	mV
$\Delta V_{AB} $ or $\Delta V_{YZ} $	Change in differential output voltage magnitude between logic states	See Figure 2	-50	50	mV
Vos(ss)	Steady-state common-mode output voltage		0.8	1.2	V
ΔVOS(SS)	Change in steady-state common-mode output voltage between logic states	See Figure 3	-50	50	mV
VOS(PP)	Peak-to-peak common-mode output voltage			150	mV
V _{A(OC)} or V _{Y(OC)}	Maximum steady-state open-circuit output voltage	05	0	2.4	V
V _{B(OC)} or V _{Z(OC)}	Maximum steady-state open-circuit output voltage	See Figure /	0	2.4	V
V _{P(H)}	Voltage overshoot, low-to-high level output	Can Figure 5		1.2V _{SS}	V
V _{P(L)}	Voltage overshoot, high-to-low level output	See Figure 2 480 65 de See Figure 2 -50 5 0.8 1. See Figure 3 -50 5 15 0 2. See Figure 7 0 2. See Figure 5 -0.2VSS VIH = 2 V 0 1 VIL = 0.8 V 0 1 See Figure 4 2 Y) -1.4 V \leq (VY or VZ) \leq 3.8 V, Other output at 1.2 V -15 1 -1.4 V \leq (VY or VZ) \leq 3.8 V, Other output at 1.2 V -15 1		V	
lιΗ	High-level input current	$V_{IH} = 2 V$	0	10	μΑ
IIL	Low-level input current	V _{IL} = 0.8 V	0	10	μΑ
los	Differential short-circuit output current	See Figure 4		24	mA
loz	High-impedance state output current (driver only)		-15	10	μΑ
lO(OFF)	Power-off output current (driver only)	V _{CC} ≤ 1.5 V,	-10	10	μΑ

[†] The algebraic convention, in which the least positive (most negative) limit is designated as minimum, is used in this data sheet.



[‡] All typical values are at 25°C and with a 3.3-V supply voltage.

[‡] All typical values are at 25°C and with a 3.3-V supply voltage.

receiver electrical characteristics over recommended operating conditions (unless otherwise noted)

	PARAMETER		TEST CONDITIONS	MIN	TYP†	MAX	UNIT	
V	Decision acing differential involved to see through ald	Type 1				50		
V _{IT+}	Positive-going differential input voltage threshold	Type 2				150	mV	
V	Negative going differential input voltage threehold	Type 1					mV	
V _{IT} –	T_ Negative-going differential input voltage threshold		Table 1 and Table 2	50				
\/	Differential input values bustones V. V.	Type 1			25		\/	
VID(HYS)	Differential input voltage hysteresis, V _{IT+} – V _{IT} –	Type 2			0		mV	
Vон	High-level output voltage		$I_{OH} = -8 \text{ mA}$	2.4			V	
V_{OL}	Low-level output voltage		$I_{OL} = 8 \text{ mA}$			0.4	V	
lіН	High-level input current		V _{IH} = 2 V	-10		0	μΑ	
IIL	Low-level input current		V _{IL} = 0.8 V	-10		0	μΑ	
loz	High-impedance output current		V _O = 0 V or 3.6 V	-10		15	μΑ	

[†] All typical values are at 25°C and with a 3.3-V supply voltage.

bus input and output electrical characteritics over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
		$V_A = 3.8 \text{ V}, \qquad V_B = 1.2 \text{ V}$	0		32	
IA	Receiver input or transceiver input/output current	$V_A = 0 \text{ V or } 2.4 \text{ V}, V_B = 1.2 \text{ V}$	-20		20	μА
		$V_A = -1.4 \text{ V}, \qquad V_B = 1.2 \text{ V}$	-32		0	
		$V_B = 3.8 \text{ V}, \qquad V_A = 1.2 \text{ V}$	0		32	
lΒ	Receiver input or transceiver input/output	$V_B = 0 \text{ V or } 2.4 \text{ V}, V_A = 1.2 \text{ V}$	-20		20	μΑ
Current		$V_B = -1.4 \text{ V}, \qquad V_A = 1.2 \text{ V}$	-32		0	
I _{AB}	Receiver input or transceiver input/output differential current (I _A – I _B)	$V_A = V_B$, $-1.4 \le V_A \le 3.8 \text{ V}$	-4		4	μА
		$V_A = 3.8 \text{ V}, \qquad V_B = 1.2 \text{ V}, V_{CC} \le 1.5 \text{ V}$	0		32	μА
IA(OFF)	Receiver input or transceiver input/output power-off current	$V_A = 0 \text{ V or } 2.4 \text{ V}, V_B = 1.2 \text{ V}, V_{CC} \le 1.5 \text{ V}$	-20		20	
, ,	power-on current	$V_A = -1.4 \text{ V}, \qquad V_B = 1.2 \text{ V}, V_{CC} \le 1.5 \text{ V}$	-32		0	
		$V_B = 3.8 \text{ V}, \qquad V_A = 1.2 \text{ V}, V_{CC} \le 1.5 \text{ V}$	0		32	
I _B (OFF)	Receiver input or transceiver input/output power-off current	$V_B = 0 \text{ V or } 2.4 \text{ V}, V_A = 1.2 \text{ V}, V_{CC} \le 1.5 \text{ V}$	-20		20	μΑ
, ,	power on ourrent	$V_B = -1.4 \text{ V}, \qquad V_A = 1.2 \text{ V}, V_{CC} \le 1.5 \text{ V}$	-32		0	
I _{AB(OFF)}	Receiver input or transceiver input/output power-off differential current $(I_A - I_B)$	$V_A = V_B$, $-1.4 \le V_A \le 3.8 \text{ V}$, $V_{CC} \le 1.5 \text{ V}$	-4		4	μА
C _A	Receiver input, driver high-impedance output, or transceiver input/output	$V_A = 0.4 \sin(2E8\pi t) + 0.5$, $V_B = 1.2 V$		3		pF
CB	capacitance	$V_B = 0.4 \sin(2E8\pi t) + 0.5$, $V_A = 1.2 V$		3		pF

[†] All typical values are at 25°C and with a 3.3-V supply voltage.



SN65MLVD200, SN65MLVD202 SN65MLVD204, SN65MLVD205 MULTIPOINT-LVDS LINE DRIVERS AND RECEIVERS

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driver switching characteristics over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
^t PLH	Propagation delay time, low-to-high-level output		1.6	2.3	4.1	ns
tPHL	Propagation delay time, high-to-low-level output	See Figure 5	1.6	2.3	4.1	ns
t _r	Differential output signal rise time		1.5	2	3	ns
tf	Differential output signal fall time		1.5	2	3	ns
tsk(p)	Pulse skew (tpHL tpLH)			30		ps
tsk(pp)	Part-to-part skew (see Note 4)				900	ps
t _{PZH}	Propagation delay time, high-impedance-to-high-level output	See Figure 6	1.5	3.7	6.5	ns
tPZL	Propagation delay time, high-impedance-to-low-level output		1.5	3.7	6.5	ns
tPHZ	Propagation delay time, high-level-to-high-impedance output		1.3	3.5	6.8	ns
tPLZ	Propagation delay time, low-level-to-high-impedance output		1.8	3.5	6.1	ns
^t jit(per)	Period jitter, rms (1 standard deviation) (see Notes 5 and 6)	50-MHz clock input (see Figure 8)		23		ps
tjit(cc)	Cycle-to-cycle jitter, peak (see Notes 5 and 6)	50-MHz clock input (see Figure 8)		180		ps
tjit(pp)	Peak-to-peak jitter, (see Notes 5, 7, and 8)	100 Mbps 2 ¹⁵ –1 PRBS input (see Figure 8)		210		ps

[†] All typical values are at 25°C and with a 3.3-V supply voltage.

- NOTES: 4. $t_{sk(pp)}$ is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.
 - 5. Jitter parameters are based on design and characterization. Stimulus system jitter of 11 ps t_{jit(per)}, 43 ps t_{jit(cc)}, or 54 ps t_{jit(pp)} have been subtracted from the values.
 - 6. Input voltage = 0 V to V_{CC} , t_{Γ} = t_{f} \leq 1 ns (20% to 80%), measured over 30k samples.
 - 7. Input voltage = 0 V to V_{CC} , $t_f = t_f \le 1$ ns (20% to 80%), measured over 100k samples.
 - 8. Peak-to-peak jitter includes jitter due to pulse skew $(t_{sk(D)})$.



SN65MLVD200, SN65MLVD202 SN65MLVD204, SN65MLVD205 MULTIPOINT-LVDS LINE DRIVERS AND RECEIVERS

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receiver switching characteristics over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST CONDITIONS		MIN	TYP†	MAX	UNIT	
tPLH	Propagation delay time, low-to-high-level output			3	5	6.7	ns	
tPHL	Propagation delay time, high-to-low-level output		3	4.6	6.7	ns		
t _{sk(p)}	Pulse skew (tpHL tpLH)	0 5 = 5 0 - 5 = - 40		400		ps		
t _{sk(pp)}	Part-to-part skew (see Note 9)	C _L = 5 pF, See Figure 10				1.5	ns	
t _r	Output signal rise time		8.0	1.4	2	ns		
t _f	Output signal fall time		0.8	1.5	2	ns		
t _{PLH}	Propagation delay time, low-to-high-level output			3.4	5.8	9	ns	
tPHL	Propagation delay time, high-to-low-level output			3.4	5.4	9	ns	
t _{sk(p)}	Pulse skew (tpHL tpLH)				400		ps	
tsk(pp)	Part-to-part skew (see Note 9)	C _L = 15 pF, See Figure 10			2.5	ns		
t _r	Output signal rise time	1	1	2	2.6	ns		
tf	Output signal fall time	1	1	1.4	2.6	ns		
^t PHZ	Propagation delay time, high-level-to-high-impedance output	See Figure 11		4.5	6	15	ns	
^t PLZ	Propagation delay time, low-level-to-high-impedance output			2	3.4	5	ns	
^t PZH	Propagation delay time, high-impedance-to-high-level output			3.5	9.8	15	ns	
tPZL	Propagation delay time, high-impedance-to-low-level output			4	8.7	15	ns	
	Period jitter, rms (1 standard deviation)	50-MHz clock input	Type 1		10			
^t jit(per)	(see Notes 10 and 11)	(see Figure 12)	Type 2		10		ps	
	0 1	50-MHz clock input Type			93			
^t jit(cc)	Cycle-to-cycle jitter, peak (see Notes 10 and 11)	(see Figure 12)	Type 2		86		ps	
		100 Mbps 2 ¹⁵ –1 PRBS	Type 1	e 1 850				
^t jit(pp)	Peak-to-peak jitter, (see Notes 10, 12, and 13)	input (see Figure 12)	Type 2		790		ps	

[†] All typical values are at 25°C and with a 3.3-V supply voltage.

NOTES: 9. t_{sk(pp)} is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.

- 10. Jitter parameters are based on design and characterization. Stimulus system jitter of 11 ps t_{jit(per)}, 43 ps t_{jit(cc)}, or 54 ps t_{jit(pp)} have been subtracted from the values.
- 11. Differential input voltage = 250 mV_{p-p} (Type 1) or 500 mV_{p-p} (Type 2), $V_{CM} = 1 \text{ V}$, $t_r = t_f \le 1 \text{ ns}$ (20% to 80%), measured over 30k samples.
- 12. Differential input voltage = 250 mV $_{p-p}$ (Type 1) or 500 mV $_{p-p}$ (Type 2), V_{CM} = 1 V, t_f = $t_f \le 1$ ns (20% to 80%), measured over 100k samples.
- 13. Peak-to-peak jitter includes jitter due to pulse skew $(t_{sk(p)})$.



PARAMETER MEASUREMENT INFORMATION

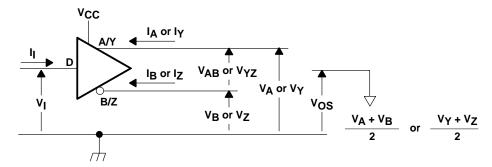
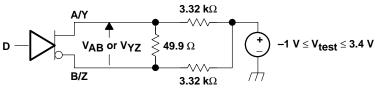
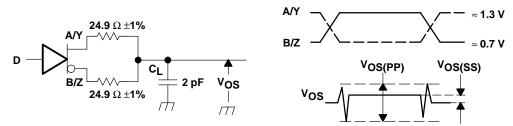


Figure 1. Driver Voltage and Current Definitions



NOTE: All resistors are 1% tolerance.

Figure 2. Differential Output Voltage Test Circuit



NOTE: All input pulses are supplied by a generator having the following characteristics: t_r or t_f ≤1 ns, pulse repetition rate (PRR) = 0.25 Mpps, pulse width = 500 ±10 ns. C_L includes instrumentation and fixture capacitance within 0,06 m of the D.U.T. The measurement of V_{OS(PP)} is made on test equipment with a –3-dB bandwidth of at least 1 GHz.

Figure 3. Test Circuit and Definitions for the Driver Common-Mode Output Voltage

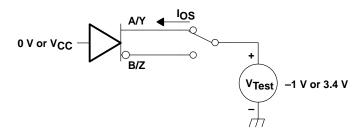
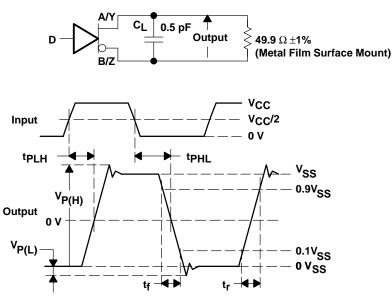


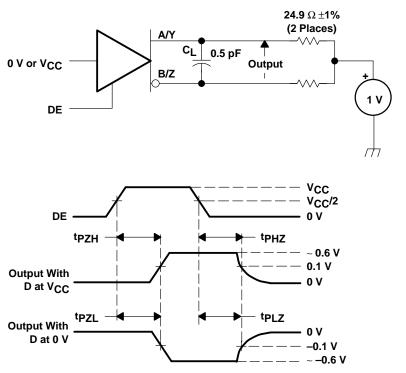
Figure 4. Driver Short-Circuit Test Circuit

PARAMETER MEASUREMENT INFORMATION



NOTE: All input pulses are supplied by a generator having the following characteristics: t_{Γ} or $t_{\Gamma} \le 1$ ns, pulse repetition rate (PRR) = 1 Mpps, pulse width = 0.5 $\pm 0.05 \,\mu s$. C_{L} includes instrumentation and fixture capacitance within 0,06 m of the D.U.T.

Figure 5. Driver Test Circuit, Timing, and Voltage Definitions for the Differential Output Signal



NOTE: All input pulses are supplied by a generator having the following characteristics: t_{Γ} or $t_{\Gamma} \le 1$ ns, pulse repetition rate (PRR) = 0.25 Mpps, pulse width = 500 ± 10 ns. C_L includes instrumentation and fixture capacitance within 0,06 m of the D.U.T.

Figure 6. Driver Enable and DIsable Time Circuit and Definitions



PARAMETER MEASUREMENT INFORMATION

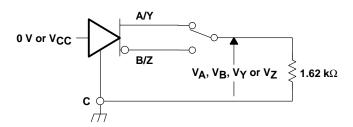
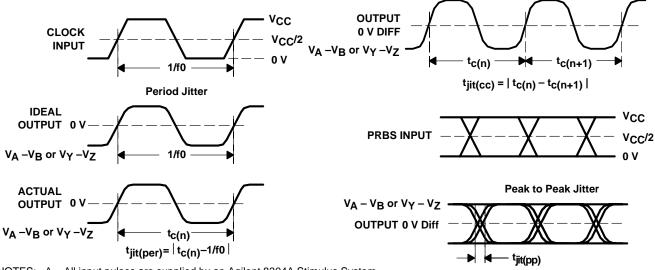


Figure 7. Maximum Steady-State Output Voltage Test Circuit



- NOTES: A. All input pulses are supplied by an Agilent 8304A Stimulus System.
 - B. The measurement is made on a TEK TDS6604 running TDSJIT3 application software
 - C. Period jitter is measured using a 100 MHz 50 \pm 1% duty cycle clock input.
 - D. Peak-to-peak jitter is measured using a 200Mbps 2¹⁵–1 PRBS input.

Figure 8. Driver Jitter Measurement Waveforms

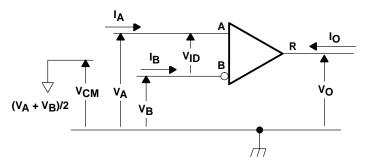


Figure 9. Receiver Voltage and Current Definitions

PARAMETER MEASUREMENT INFORMATION

Table 1. Type-1 Receiver Input Threshold Test Voltages

APPLIED VOLTAGES		RESULTING DIFFERENTIAL INPUT VOLTAGE	RESULTING COMMON- MODE INPUT VOLTAGE	RECEIVER OUTPUT
٧A	٧B	V _{ID}	V _{CM}	v _o
3.425 V	3.375 V	50 mV	3.4 V	Н
3.375 V	3.425 V	−50 mV	3.4 V	L
-0.975 V	-1.025 V	50 mV	-1.0 V	Н
-1.025 V	–0.975 V	−50 mV	-1.0 V	L
3.800 V	3.000 V	800 mV	3.4 V	Н
3.000 V	3.800 V	−800 mV	3.4 V	L
-0.600 V	-1.400 V	800 mV	−1.0 V	Н
-1.400 V	-0.600 V	−800 mV	-1.0 V	L

NOTE: H= high level, L = low level. Output state assumes receiver is enabled (RE is Low).

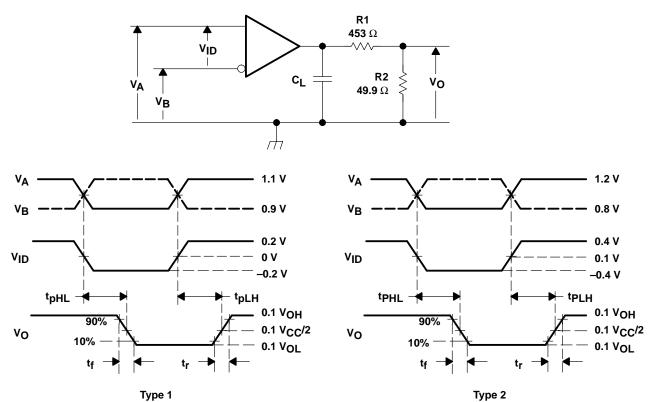
Table 2. Type-2 Receiver Input Threshold Test Voltages

APPLIED VOLTAGES		RESULTING DIFFERENTIAL INPUT VOLTAGE	RESULTING COMMON- MODE INPUT VOLTAGE	RECEIVER OUTPUT
٧A	٧ _B	V_{ID}	V _{CM}	v _o
3.475 V	3.325 V	150 mV	3.4 V	Н
3.425 V	3.375 V	50 mV	3.4 V	L
-0.925 V	–1.075 V	150 mV	-1.0 V	Н
-0.975 V	–1.025 V	50 mV	-1.0 V	L
3.800 V	3.000 V	800 mV	3.4 V	Н
3.000 V	3.800 V	−800 mV	3.4 V	L
-0.600 V	-1.400 V	800 mV	−1.0 V	Н
-1.400 V	-0.600 V	−800 mV	-1.0 V	L

NOTE: H= high level, L = low level. Output state assumes receiver is enabled (\overline{RE} is Low).



PARAMETER MEASUREMENT INFORMATION

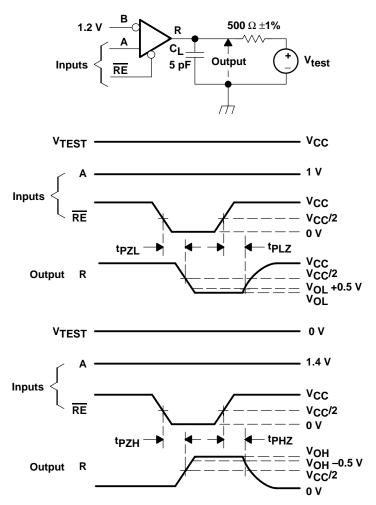


NOTES: A. All input pulses are supplied by a generator having the following characteristics: t_f or $t_f \le 1$ ns, pulse repetition rate (PRR) = 1 Mpps, pulse width = $0.5 \pm 0.05 \,\mu s$.

- B. Resistors are 1% tolerance, metal film, and surface mount.
- C. C_L is 20% tolerance, low-loss ceramic, and surface mount.
- D. R1 and C_L are located within 2 cm of the D.U.T.
- E. R2 is located within 15 cm of the D.U.T.

Figure 10. Receiver Timing Test Circuit and Waveforms

PARAMETER MEASUREMENT INFORMATION

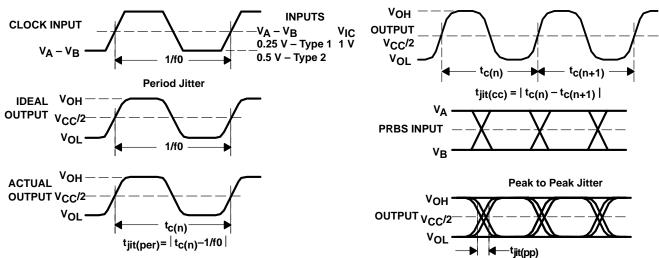


NOTE: All input pulses are supplied by a generator having the following characteristics: t_{Γ} or $t_{f} \le 1$ ns, pulse repetition rate (PRR) = 0.25 Mpps, pulse width = 500 ± 10 ns. C_{L} includes instrumentation and fixture capacitance within 0,06 m of the D.U.T.

Figure 11. Receiver Enable/Disable Time Test Circuit and Waveforms



PARAMETER MEASUREMENT INFORMATION

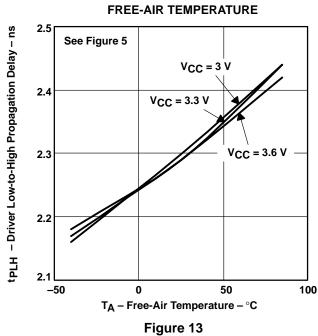


NOTES: A. All input pulses are supplied by an Agilent 8304A Stimulus System.

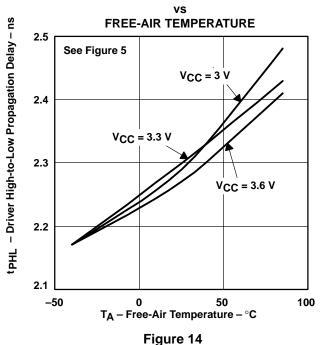
- B. The measurement is made on a TEK TDS6604 running TDSJIT3 application software
- C. Period jitter is measured using a 100 MHz 50 \pm 1% duty cycle clock input.
- D. Peak-to-peak jitter is measured using a 200Mbps 2¹⁵–1 PRBS input.

Figure 12. Receiver Jitter Measurement Waveforms

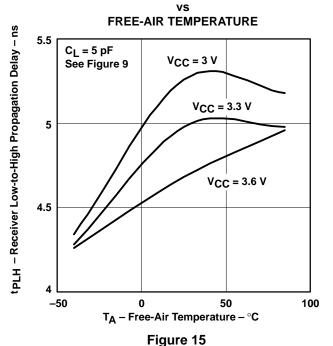
DRIVER LOW-TO-HIGH PROPAGATION DELAY vs



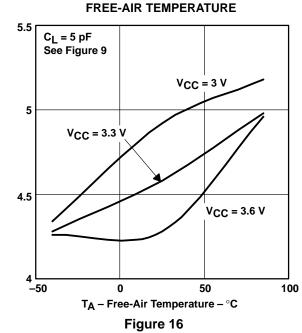
DRIVER HIGH-TO-LOW PROPAGATION DELAY



RECEIVER LOW-TO-HIGH PROPAGATION DELAY



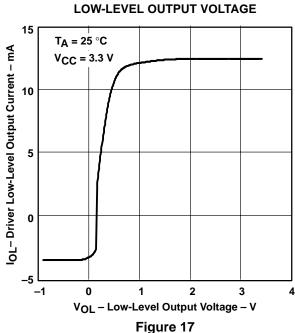
RECEIVER HIGH-TO-LOW PROPAGATION DELAY vs



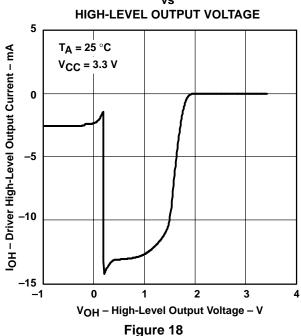


tPHL - Receiver High-to-Low Propagation Delay - ns

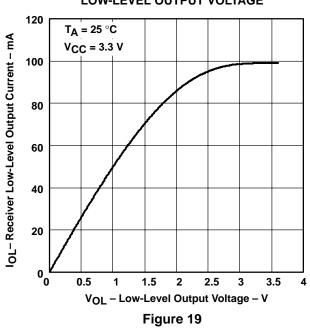
DRIVER LOW-LEVEL OUTPUT CURRENT vs



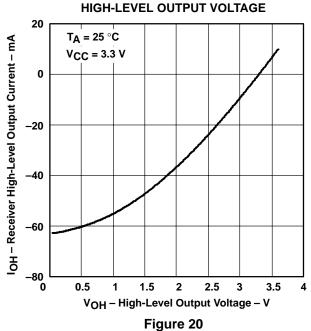
DRIVER HIGH-LEVEL OUTPUT CURRENT vs

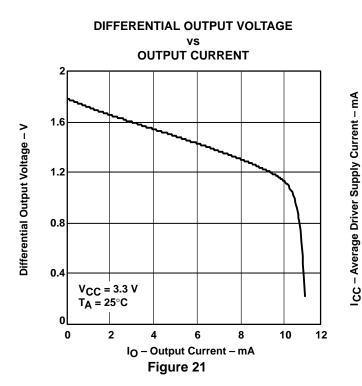


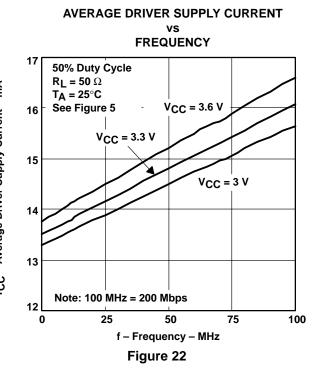
RECEIVER LOW-LEVEL OUTPUT CURRENT vs LOW-LEVEL OUTPUT VOLTAGE



RECEIVER HIGH-LEVEL OUTPUT CURRENT vs

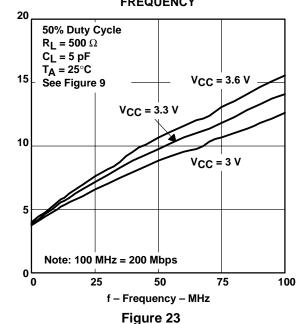


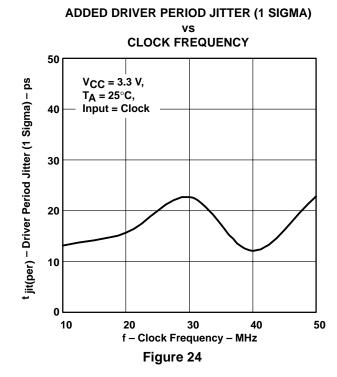




٧S **FREQUENCY** 20 50% Duty Cycle ICC - Average Receiver Supply Current - mA $R_L = 500 \Omega$ $C_L = 5 pF$ T_A = 25°C 15 $V_{CC} = 3.6 V$ See Figure 9 $V_{CC} = 3.3 V$

AVERAGE RECEIVER SUPPLY CURRENT

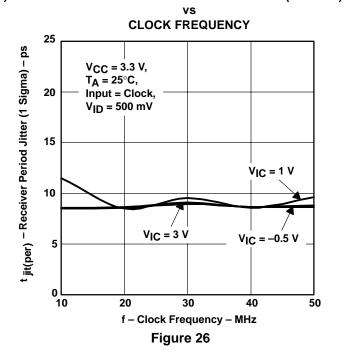




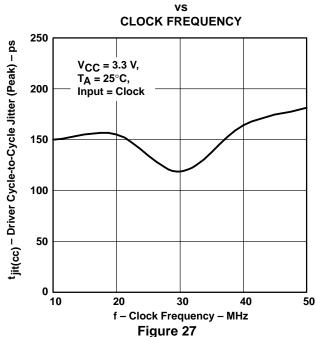
ADDED TYPE 1 RECEIVER PERIOD JITTER (1 SIGMA)

CLOCK FREQUENCY 25 t jit(per) - Receiver Period Jitter (1 Sigma) - ps $V_{CC} = 3.3 V,$ $T_A = 25^{\circ}C$ Input = Clock, 20 $V_{ID} = 250 \text{ mV}$ $V_{IC} = -0.5 V$ **VIC = 3 V** 15 10 V_{IC} = 1 V 5 10 30 40 50 f - Clock Frequency - MHz Figure 25

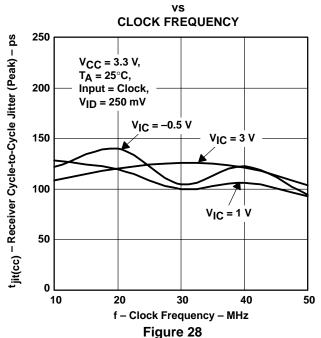
ADDED TYPE 2 RECEIVER PERIOD JITTER (1 SIGMA)



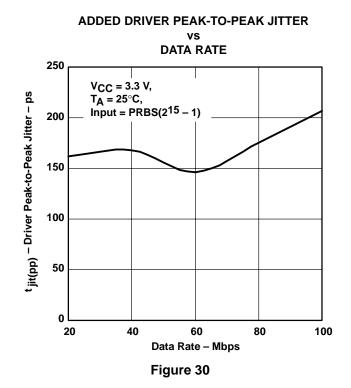
ADDED DRIVER CYCLE-TO-CYCLE JITTER (PEAK)



ADDED TYPE 1 RECEIVER CYCLE-TO-CYCLE JITTER (PEAK)

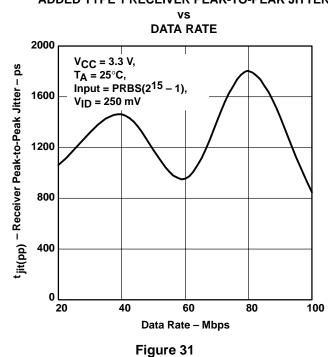


ADDED TYPE 2 RECEIVER CYCLE-TO-CYCLE JITTER (PEAK) vs **CLOCK FREQUENCY** 250 tjit(cc) – Receiver Cycle-to-Cycle Jitter (Peak) – ps $V_{CC} = 3.3 V$ $T_A = 25^{\circ}C$ 200 Input = Clock, V_{ID} = 500 mV 150 $V_{IC} = -0.5 V$ V_{IC} = 1 V 100 $V_{IC} = 3 V$ 50 10 30 50 f - Clock Frequency - MHz



ADDED TYPE 1 RECEIVER PEAK-TO-PEAK JITTER

Figure 29



vs **DATA RATE** 2000 $V_{CC} = 3.3 V$ $T_A = 25^{\circ}C$ Input = $PRBS(2^{15} - 1)$, jit(pp) - Receiver Peak-to-Peak Jitter 1600 $V_{ID} = 500 \text{ mV}$ 1200 800 400

ADDED TYPE 2 RECEIVER PEAK-TO-PEAK JITTER

Data Rate - Mbps Figure 32

60

100

0

20

40

APPLICATION INFORMATION

Type-1 and Type-2 receivers

The M-LVDS standard defines Type-1 and Type-2 receivers. Type-1 receivers include no provisions for failsafe and have their differential input voltage thresholds near zero volts. Type-2 receivers have their differential input voltage thresholds offset from zero volts to detect the absence of a voltage difference. Type-1 receivers maximize the differential noise margin and are intended for maximum signaling rates. Type-2 receivers are intended for control signals and slower signaling rates. The impact on receiver output by the offset input can be seen in Table 3 and Figure 33.

Table 3. M-LVDS Receiver Input Voltage Threshold Requirements

Receiver Type	Output Low	Output High
1	$-2.4 \text{ V} \le \text{V}_{1D} \le -0.05 \text{ V}$	$0.05 \text{ V} \le \text{V}_{1D} \le 2.4 \text{ V}$
2	$-2.4 \text{ V} \le \text{V}_{1D} \le 0.05 \text{ V}$	$0.15 \text{ V} \le \text{V}_{1D} \le 2.4 \text{ V}$

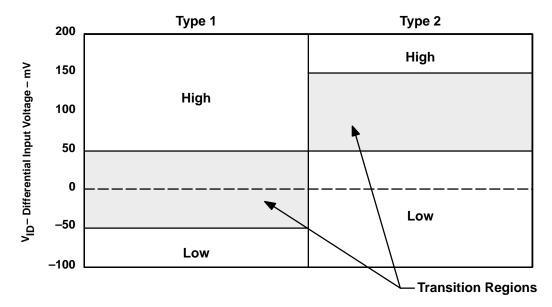


Figure 33. Receiver Differential Input Voltage Showing Transition Region

APPLICATION INFORMATION

comparison of M-LVDS with RS-485

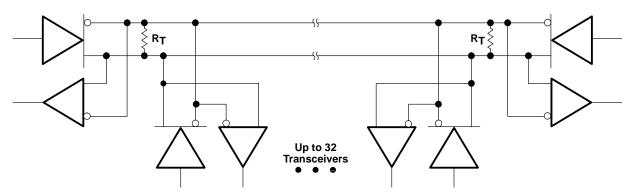
RS-485 applications are similar to M-LVDS. The two standards define balanced multipoint systems with some basic architecture changes due to the different applications. Table 4 gives a high-level comparison of the two different technologies.

Table 4. Comparison Between M-LVDS and RS-485 Standards

	Number of Loads	Differential Voltage Range	Common-Mode Voltage Range	Maximum Signaling Rate (Mbps)	Receiver Minimum Threshold
RS-485	32	1.5 V to 5 V	–7 V to 12 V	50 Mbps	±200 mV
M-LVDS	32	480 mV to 650 mV	–1 V to 3.4 V	500 Mbps	±50 mV

It can be seen that with the greater differential output voltage and common-mode voltage range of the RS-485-type device, it can handle longer signaling distances where M-LVDS offers ten times the signaling rate of RS-485.

SN65MLVD200 SN65MLVD200



NOTE A: The line should be terminated at both ends in its characteristic impedance (R_T = Z_O). Stub lengths off the main line should be kept as short as possible.

Figure 34. Typical Application Circuit



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